

PC4N29V/PC4N30V PC4N32V/PC4N33V

High Transfer Efficiency, General Purpose Type Photocoupler

* Lead forming type (I type) is also available. (PC4N29VI/PC4N30VI/PC4N32VI/PC4N33VI) (Page 482)

Features

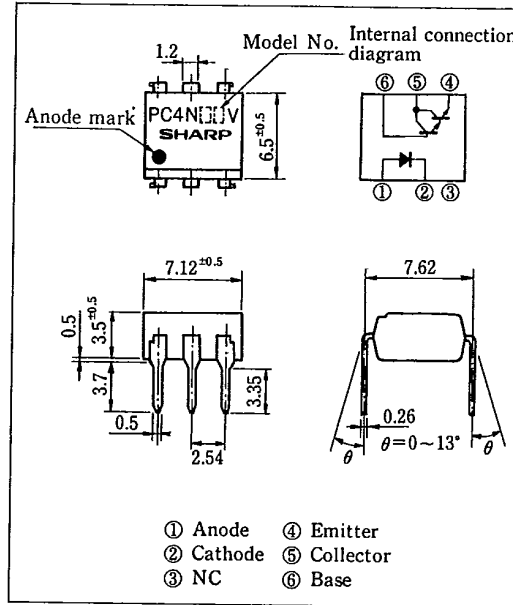
- High current transfer ratio
PC4N29V, PC4N30V
(CTR : MIN. 100% at $I_F=10\text{mA}$, $V_{CE}=10\text{V}$)
PC4N32V, PC4N33V
(CTR : MIN. 500% at $I_F=10\text{mA}$, $V_{CE}=10\text{V}$)
- Response time t_{on} : MAX. $5\mu\text{s}$ at $I_F=200\text{mA}$, $V_{CC}=10\text{V}$, $I_C=50\text{mA}$
- UL recognized, file No. E64380
TUV approved, PC4N29V/32V : No. R40184, PC4N30V/33V : No. R40185

Applications

- I/O interfaces for computers
- System appliances, measuring instruments
- Signal transmission between circuits of different potentials and impedances

Outline Dimensions

(Unit : mm)



Absolute Maximum Ratings

($T_a=25^\circ\text{C}$)

| Parameter | | Symbol | Rating | Unit |
|--------------------------|-----------------------------|-----------|------------|------------------|
| Input | Forward current | I_F | 80 | mA |
| | *1 Peak forward current | I_{FM} | 3 | A |
| | Reverse voltage | V_R | 6 | V |
| | Power dissipation | P | 150 | mW |
| Output | Collector-emitter voltage | V_{CEO} | 30 | V |
| | Emitter-collector voltage | V_{ECO} | 5 | V |
| | Collector-base voltage | V_{CBO} | 30 | V |
| | Collector current | I_C | 100 | mA |
| | Collector power dissipation | P_C | 150 | mW |
| Total power dissipation | | P_{tot} | 250 | mW |
| *2 Isolation voltage | PC4N29V,32V | V_{iso} | 2,500 | Vrms |
| | PC4N30V,33V | | 1,500 | |
| Operating temperature | | T_{opr} | -55 ~ +100 | $^\circ\text{C}$ |
| Storage temperature | | T_{stg} | -55 ~ +150 | $^\circ\text{C}$ |
| *3 Soldering temperature | | T_{sol} | 260 | $^\circ\text{C}$ |

*1 Pulse width $\leq 1\mu\text{s}$, Duty ratio = 0.001

*2 RH = 40 ~ 60%, AC for 1 minute

*3 For 10 seconds

■ Electro-optical Characteristics

T-41-83

(Ta=25°C)

| Parameter | | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--------------------------|--------------------------------------|----------------------------|---|--------------------|-----------|---------------|---------------|
| Input | Forward voltage | V_F | $I_F=10\text{mA}$ | — | 1.2 | 1.5 | V |
| | Reverse current | I_R | $V_R=4\text{V}$ | — | — | 10 | μA |
| | Terminal capacitance | C_t | $V=0, f=1\text{kHz}$ | — | 50 | — | pF |
| Output | Collector dark current | I_{CE0} | $V_{CE}=10\text{V}, I_F=0$ | — | — | 10^{-7} | A |
| | Collector-emitter breakdown voltage | BV_{CEO} | $I_C=0.1\text{mA}, I_F=0$ | 30 | — | — | V |
| | Emitter-collector breakdown voltage | BV_{ECO} | $I_E=10\mu\text{A}, I_F=0$ | 5 | — | — | V |
| | Collector-base breakdown voltage | BV_{CBO} | $I_C=0.1\text{mA}, I_F=0$ | 30 | — | — | V |
| Transfer characteristics | Current transfer ratio | PC4N29V,30V | CTR $I_F=10\text{mA}, V_{CE}=10\text{V}$ Pulse test: input pulse width = 300 μs , duty ratio ≤ 0.02 | 100 | — | — | % |
| | | PC4N32V,33V | | 500 | — | — | % |
| | Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_F=8\text{mA}, I_C=2\text{mA}$ | — | — | 1.0 | V |
| | Isolation resistance | R_{ISO} | DC500V, RH=40~60% | 5×10^{10} | 10^{11} | — | Ω |
| | Floating capacitance | C_f | $V=0, f=1\text{MHz}$ | — | 1.0 | — | pF |
| | Response time (Turn-on time) | t_{on} | $I_F=200\text{mA}$ | — | — | 5 | μs |
| | Response time (Turn-off time) | PC4N29V,30V PC4N32V,33V | t_{off} $V_{CE}=10\text{V}, I_C=50\text{mA}$ | — | — | 40 | μs |
| | | | — | — | 100 | μs | |

Fig. 1 Forward Current vs. Ambient Temperature

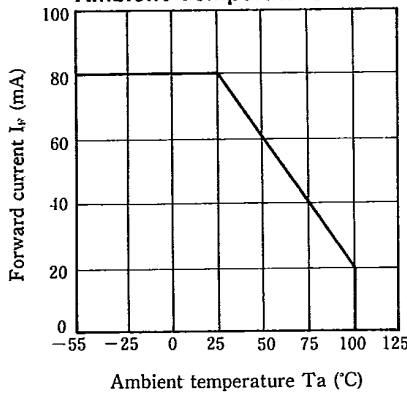
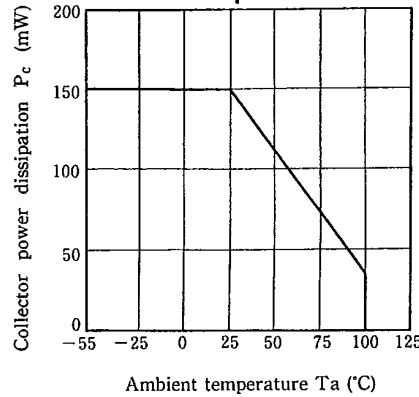


Fig. 2 Collector Power Dissipation vs. Ambient Temperature



6

Fig. 3 Forward Current vs. Forward Voltage

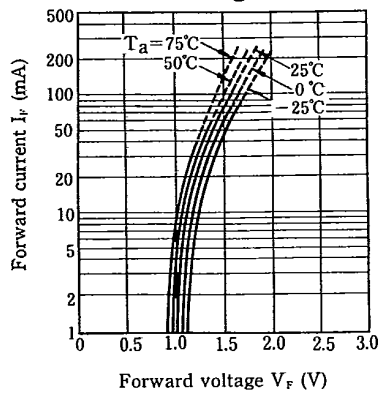


Fig. 4 Current Transfer Ratio vs. Forward Current (PC4N29V, PC4N30V)

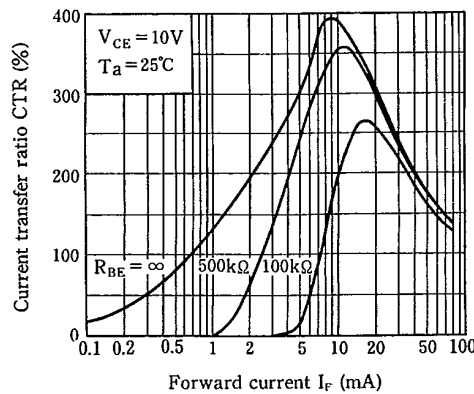


Fig. 5 Current Transfer Ratio vs. Forward Current (PC4N32V, PC4N33V)

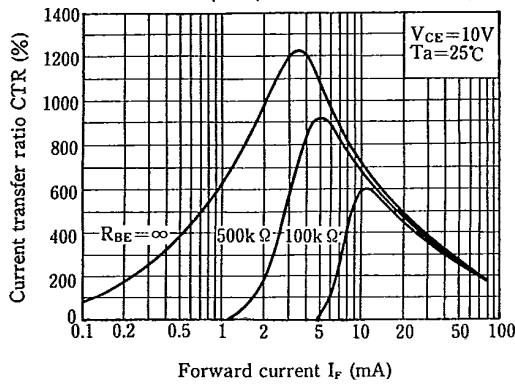


Fig. 6 Collector Current vs. Collector-emitter Voltage (PC4N29V, PC4N30V)

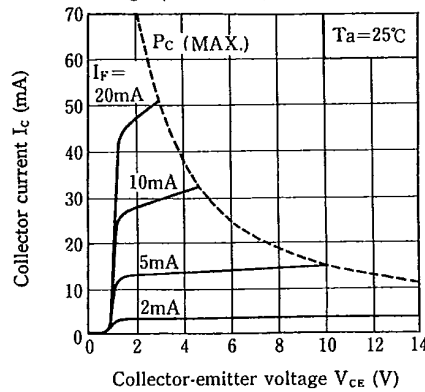


Fig. 7 Collector Current vs. Collector-emitter Voltage (PC4N32V, PC4N33V)

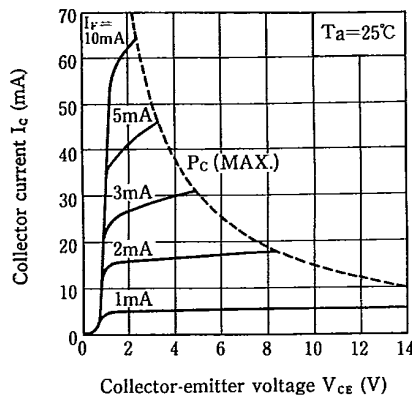


Fig. 8 Relative Current Transfer Ratio vs. Ambient Temperature

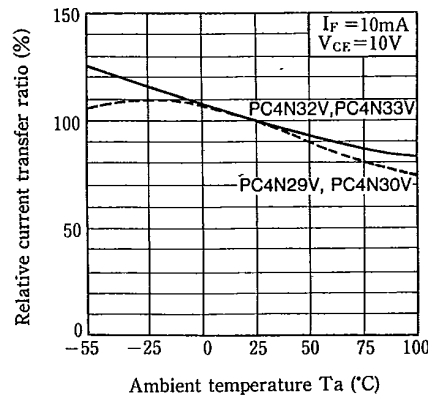


Fig. 9 Collector-emitter Saturation Voltage vs. Ambient Temperature

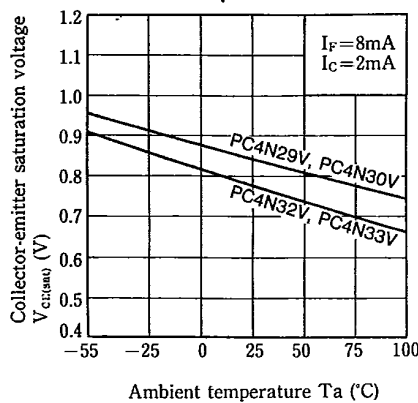


Fig. 10 Collector Dark Current vs. Ambient Temperature

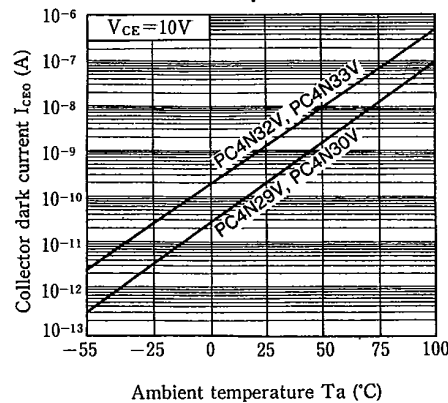


Fig. 11 Frequency Response (PC4N29V, PC4N30V)

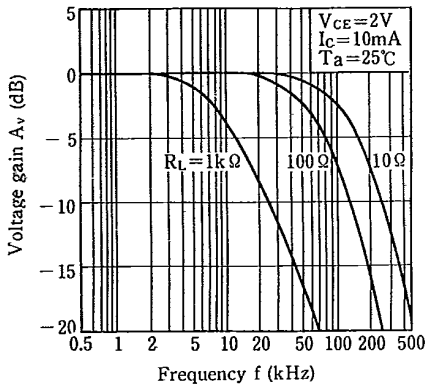


Fig. 12 Frequency Response (PC4N32V, PC4N33V)

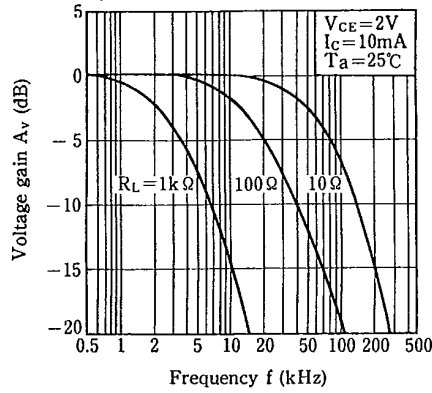


Fig. 13 Collector-emitter Saturation Voltage vs. Forward Current (PC4N29V, PC4N30V)

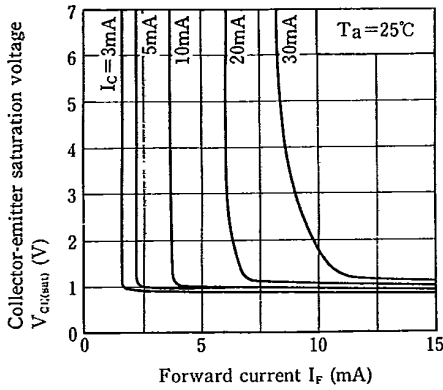
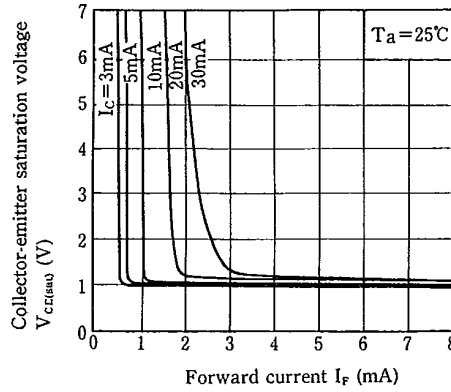
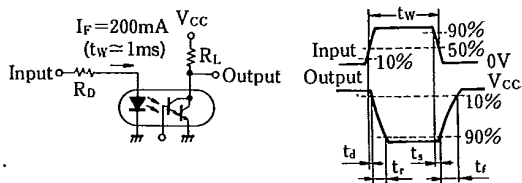


Fig. 14 Collector-emitter Saturation Voltage vs. Forward Current (PC4N32V, PC4N33V)



6

Test Circuit for Response Time



Test Circuit for Frequency Response

